

Kevin E Smith

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/6738843/publications.pdf>

Version: 2024-02-01

49
papers

1,445
citations

279798

23
h-index

315739

38
g-index

50
all docs

50
docs citations

50
times ranked

2014
citing authors

| # | ARTICLE | IF | CITATIONS |
|----|--|------|-----------|
| 1 | Effect of lattice mismatch on film morphology of the quasi-one dimensional conductor $K_{0.3}MoO_3$. RSC Advances, 2022, 12, 4521-4525. | 3.6 | 0 |
| 2 | Role of phase separation in nanocomposite indium-tin-oxide films for transparent thermoelectric applications. Journal of Materiomics, 2021, 7, 612-620. | 5.7 | 28 |
| 3 | Ironsand (Titanomagnetite-Titanohematite): Chemistry, Magnetic Properties and Direct Applications for Wireless Power Transfer. Materials, 2021, 14, 5455. | 2.9 | 4 |
| 4 | Momentum for Catalysis: How Surface Reactions Shape the RuO ₂ Flat Surface State. ACS Catalysis, 2021, 11, 1749-1757. | 11.2 | 8 |
| 5 | Methanol Adsorption on Vanadium Oxide Surfaces Observed by Ambient Pressure X-ray Photoelectron Spectroscopy. Journal of Physical Chemistry C, 2021, 125, 23192-23204. | 3.1 | 1 |
| 6 | The Itinerant 2D Electron Gas of the Indium Oxide (111) Surface: Implications for Carbon and Energy Conversion Applications. Small, 2020, 16, e1903321. | 10.0 | 17 |
| 7 | Influence of Carrier Density and Energy Barrier Scattering on a High Seebeck Coefficient and Power Factor in Transparent Thermoelectric Copper Iodide. ACS Applied Energy Materials, 2020, 3, 10037-10044. | 5.1 | 49 |
| 8 | Water adsorption on vanadium oxide thin films in ambient relative humidity. Journal of Chemical Physics, 2020, 152, 044715. | 3.0 | 27 |
| 9 | Large Area 2D/3D MoS ₂ MoO ₂ Heterostructures with Thermally Stable Exciton and Intriguing Electrical Transport Behaviors. Advanced Electronic Materials, 2017, 3, 1600335. | 5.1 | 25 |
| 10 | A soft X-ray spectroscopic perspective of electron localization and transport in tungsten doped bismuth vanadate single crystals. Physical Chemistry Chemical Physics, 2016, 18, 31958-31965. | 2.8 | 16 |
| 11 | Transport behavior and electronic structure of phase pure VO ₂ thin films grown on <i>c</i> -plane sapphire under different O ₂ partial pressure. Journal of Applied Physics, 2013, 114, . | 2.5 | 38 |
| 12 | Metal-insulator transition induced in CaVO ₃ thin films. Journal of Applied Physics, 2013, 113, . | 2.5 | 31 |
| 13 | Boron Subphthalocyanine Chloride as an Electron Acceptor for High Voltage Fullerene Free Organic Photovoltaics. Advanced Functional Materials, 2012, 22, 561-566. | 14.9 | 89 |
| 14 | Elucidating the factors that determine the open circuit voltage in discrete heterojunction organic photovoltaic cells. Journal of Materials Chemistry, 2010, 20, 1173-1178. | 6.7 | 25 |
| 15 | Electronic structure of the organic semiconductor copper tetraphenylporphyrin (CuTPP). Applied Surface Science, 2009, 256, 720-725. | 6.1 | 20 |
| 16 | Soft X-ray spectroscopy study of electronic structure in the organic semiconductor titanyl phthalocyanine (TiO-Pc). Journal of Materials Chemistry, 2008, 18, 1792. | 6.7 | 21 |
| 17 | Observation of quantized subband states and evidence for surface electron accumulation in CdO from angle-resolved photoemission spectroscopy. Physical Review B, 2008, 78, . | 3.2 | 75 |
| 18 | Electronic structure of single-crystal rocksalt CdO studied by soft x-ray spectroscopies and <i>ab initio</i> calculations. Physical Review B, 2008, 77, . | 3.2 | 35 |

| # | ARTICLE | IF | CITATIONS |
|----|---|-----|-----------|
| 19 | Electronic structure of the organic semiconductor vanadyl phthalocyanine (VO-Pc). Journal of Materials Chemistry, 2007, 17, 1276. | 6.7 | 38 |
| 20 | Experimental and theoretical study of the electronic structures of $\hat{1}\pm$ -PbO and $\hat{1}^2$ -PbO ₂ . Journal of Materials Chemistry, 2007, 17, 267-277. | 6.7 | 104 |
| 21 | Photoemission study of sulfur and oxygen adsorption on GaN(). Surface Science, 2006, 600, 116-123. | 1.9 | 12 |
| 22 | Electronic structure in thin film organic semiconductors studied using soft X-ray emission and resonant inelastic X-ray scattering. Thin Solid Films, 2006, 515, 394-400. | 1.8 | 4 |
| 23 | Quantized Electron Accumulation States in Indium Nitride Studied by Angle-Resolved Photoemission Spectroscopy. Physical Review Letters, 2006, 97, 237601. | 7.8 | 103 |
| 24 | Electronic excitations in vanadium oxide phthalocyanine studied via resonant soft X-ray emission and resonant inelastic X-ray scattering. Chemical Physics Letters, 2005, 413, 95-99. | 2.6 | 18 |
| 25 | Experimental and theoretical study of the electronic structure of HgO and Ti ₂ O ₃ . Physical Review B, 2005, 71, . | 3.2 | 51 |
| 26 | Surface electronic structure of the organic superconductor $\hat{1}^2$ -(ET) ₂ Cu(NCS) ₂ studied via photoemission microscopy. Surface Science, 2004, 551, 219-227. | 1.9 | 6 |
| 27 | Electronic structure near the Fermi level of the organic semiconductor copper phthalocyanine. Chemical Physics Letters, 2004, 390, 203-207. | 2.6 | 46 |
| 28 | On the involvement of the shallow core 5d level in the bonding in HgO. Chemical Physics Letters, 2004, 399, 98-101. | 2.6 | 26 |
| 29 | Influence of shallow core-level hybridization on the electronic structure of post-transition-metal oxides studied using soft X-ray emission and absorption. Physical Review B, 2003, 68, . | 3.2 | 115 |
| 30 | Surface degradation of In _x Ga _{1-x} N thin films by sputter-anneal processing: A scanning photoemission microscope study. Journal of Applied Physics, 2003, 94, 5820-5825. | 2.5 | 4 |
| 31 | Studies of the electronic structure in complex materials using synchrotron radiation-excited soft x-ray emission spectroscopy at the NSLS. Synchrotron Radiation News, 2002, 15, 11-15. | 0.8 | 2 |
| 32 | X-ray Spectroscopic Studies of the Bulk Electronic Structure of InGaN Alloys. Materials Research Society Symposia Proceedings, 2002, 743, L10.11.1. | 0.1 | 0 |
| 33 | Soft X-Ray Emission and Resonant Inelastic X-Ray Scattering Studies of Transition Metal Oxides.. Materials Research Society Symposia Proceedings, 2002, 755, 1. | 0.1 | 2 |
| 34 | Electronic structure in low dimensional and correlated transition metal oxides: high resolution photoemission and X-ray emission studies. Solid State Sciences, 2002, 4, 359-378. | 3.2 | 10 |
| 35 | Recent high resolution photoemission studies of electronic structure in quasi-one-dimensional conductors. Journal of Electron Spectroscopy and Related Phenomena, 2001, 117-118, 517-526. | 1.7 | 3 |
| 36 | Surface electronic structure of p-type GaN(0001 $\bar{1}$,,). Surface Science, 2000, 467, L827-L833. | 1.9 | 23 |

| # | ARTICLE | IF | CITATIONS |
|----|--|-----|-----------|
| 37 | Electronic Structure near the Fermi Surface in the Quasi-One-Dimensional Conductor $\text{Li}_{0.9}\text{Mo}_6\text{O}_{17}$. <i>Physical Review Letters</i> , 1999, 83, 1235-1238. | 7.8 | 38 |
| 38 | Molecular components of the bulk electronic structure of organic conductors: a soft X-ray absorption and soft X-ray emission spectroscopy approach. <i>Journal of Electron Spectroscopy and Related Phenomena</i> , 1999, 101-103, 539-544. | 1.7 | 0 |
| 39 | Density of states, hybridization, and band-gap evolution in $\text{Al}_x\text{Ga}_{1-x}$ alloys. <i>Physical Review B</i> , 1998, 58, 1928-1933. | 3.2 | 76 |
| 40 | Soft x-ray emission studies of the bulk electronic structure of AlN, GaN, and $\text{Al}_{0.5}\text{Ga}_{0.5}\text{N}$. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1998, 16, 2250. | 1.6 | 15 |
| 41 | Surface and bulk electronic structure of thin-film wurtzite GaN. <i>Physical Review B</i> , 1997, 56, 10271-10275. | 3.2 | 108 |
| 42 | Photoemission Study of The Electronic Structure of Wurtzite GaN(0001) Surfaces. <i>Materials Research Society Symposia Proceedings</i> , 1997, 482, 802. | 0.1 | 4 |
| 43 | Electronic Structure of the Organic Metals $\hat{\text{I}}^{\text{a}}\text{-Et}_2\text{Cu}(\text{SCN})_2$ and $\hat{\text{I}}^{\text{a}}\text{-Et}_2\text{Cu}[\text{N}(\text{Cn})_2]\text{Br}$ Measured by Soft X-Ray Emission and Soft X-Ray Absorption. <i>Materials Research Society Symposia Proceedings</i> , 1997, 488, 489. | 0.1 | 0 |
| 44 | Bulk and Surface Electronic Structure of GaN Measured Using Angle-Resolved Photoemission, Soft X-ray Emission and Soft X-ray Absorption. <i>Materials Research Society Symposia Proceedings</i> , 1996, 449, 787. | 0.1 | 5 |
| 45 | Dominant role of the surface in photoemission from quasi-one dimensional conductors: $\text{K}_0.3\text{MoO}_3$. <i>Journal of Physics and Chemistry of Solids</i> , 1996, 57, 1803-1809. | 4.0 | 7 |
| 46 | Electronic structure of surface defects in $\text{K}_0.3\text{MoO}_3$. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 1994, 12, 2196-2200. | 2.1 | 29 |
| 47 | Defects in Quasi-One Dimensional Oxide Conductors: $\text{K}_0.3\text{MoO}_3$. <i>Materials Research Society Symposia Proceedings</i> , 1994, 375, 133. | 0.1 | 0 |
| 48 | Fermi surface of a quasi-one-dimensional oxide conductor. <i>Physical Review Letters</i> , 1993, 70, 3772-3775. | 7.8 | 43 |
| 49 | The electronic structure of solids studied using angle resolved photoemission spectroscopy. <i>Progress in Solid State Chemistry</i> , 1991, 21, 49-131. | 7.2 | 44 |